

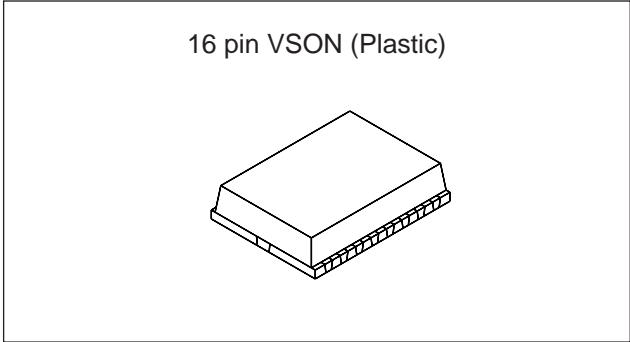
**High Power 2 × 4 Antenna Switch MMIC with Integrated Control Logic**

**Description**

The CXG1090EN is a high power antenna switch MMIC. This IC is suited to connect Tx/Rx to one of 4 antennas in cellular handset such as PDC.

The CXG1090EN has the integrated control logic and can be operated with CMOS input.

This IC is designed using the Sony's GaAs J-FET process which enable the CXG1090EN to be operated with low voltage.



**Features**

- Low insertion loss: 0.30dB (Typ.)@900MHz, 0.40dB (Typ.)@1.5GHz
- Small package: 16-pin VSON
- High power handling: PI dB: 37dBm
- CMOS compatible input control
- Low bias voltage:  $V_{DD} = 3.0V$

**Applications**

2 × 4 antenna switch for digital cellular telephones such as PDC handsets

**Structure**

GaAs J-FET MMIC

**Absolute Maximum Ratings**

• Bias voltage	$V_{DD}$	7	V @ $T_a = 25^{\circ}C$
• Control voltage	$V_{CTL}$	5	V @ $T_a = 25^{\circ}C$
• Operating temperature	$T_{opr}$	-35 to +85	$^{\circ}C$
• Storage temperature	$T_{stg}$	-65 to +150	$^{\circ}C$

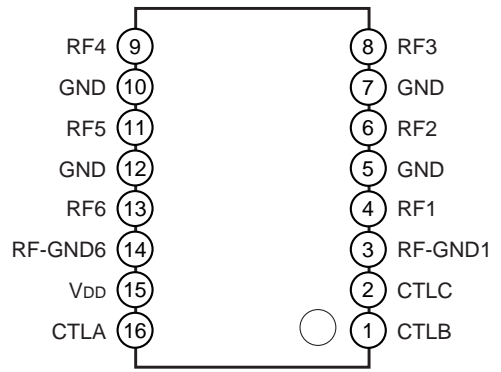
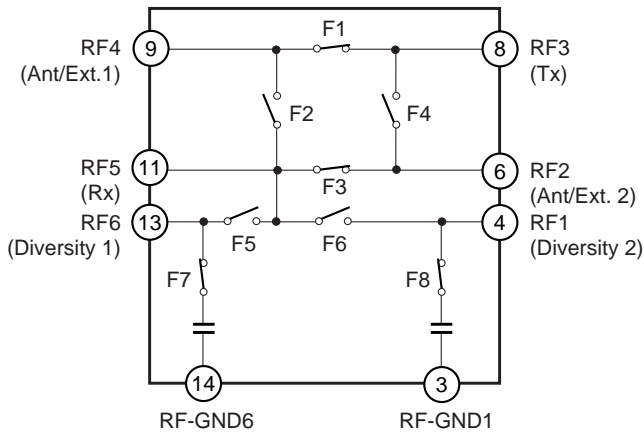
**Note on Handling**

GaAs MMICs are ESD sensitive devices. Special handling precautions are required.

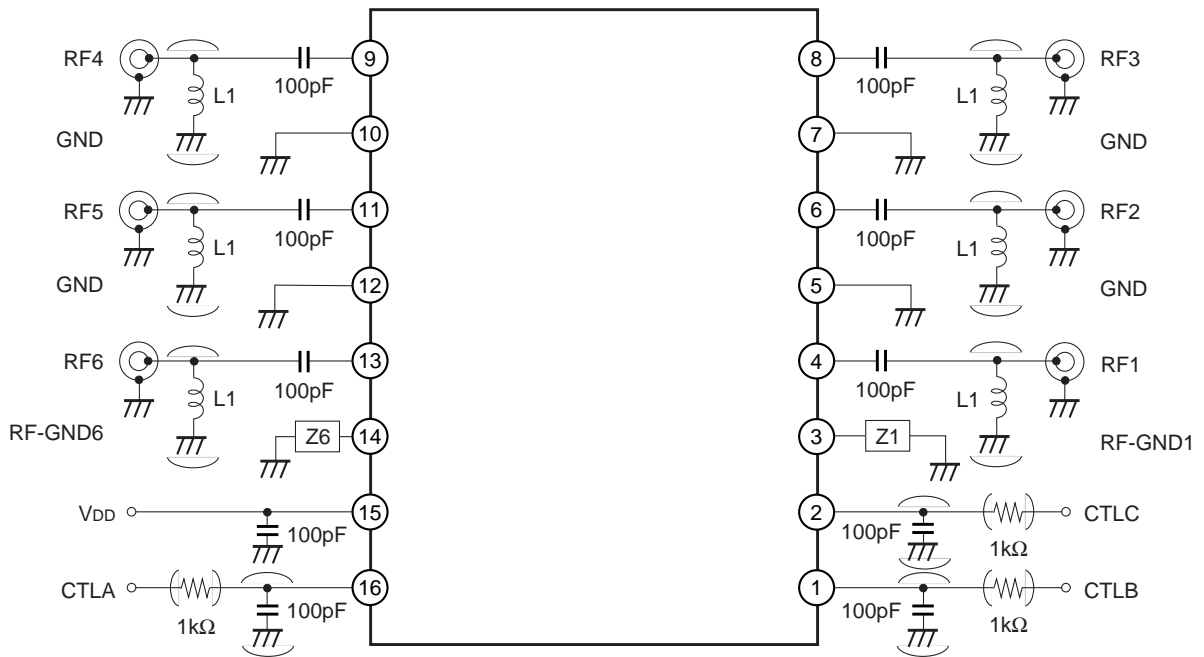
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Block Diagram

Pin Configuration



Recommended Circuit



- \* DC blocking capacitors (CRF) are needed.
- \* Recommended to use bypass capacitors (C<sub>bypass</sub>).
- \* Recommended to use control resistors (R<sub>CTL</sub>), when it is necessary to improve the electrostatic discharge strength (ESD).

**Truth Table**

Control			ON	F1	F2	F3	F4	F5	F6	F7	F8
CTLA	CTLB	CTL C									
H	L	L	RF3 → RF2	OFF	ON	OFF	ON	OFF	OFF	ON	ON
H	L	H	RF3 → RF4	ON	OFF	ON	OFF	OFF	OFF	ON	ON
L	L	L	RF5 → RF2	ON	OFF	ON	OFF	OFF	OFF	ON	ON
L	L	H	RF5 → RF4	OFF	ON	OFF	ON	OFF	OFF	ON	ON
L	H	L	RF5 → RF6	OFF	OFF	OFF	OFF	ON	OFF	OFF	ON
L	H	H	RF5 → RF1	OFF	OFF	OFF	OFF	OFF	ON	ON	OFF

**DC Bias Condition**

(Ta = 25°C)

Item	Min.	Typ.	Max.	Unit
V <sub>CTL (H)</sub> A to C	2.4		3.6	V
V <sub>CTL (L)</sub> A to C	0		0.8	V
V <sub>DD</sub>	2.8		3.2	V

## Electrical Characteristics 1

(V<sub>CTL</sub> (L) = 0V, V<sub>CTL</sub> (H) = 3V, Ta = 25°C)

Item		Frequency	Condition	Min.	Typ.	Max.	Unit
Insertion loss	RF3-RF2	889 to 960MHz	Pin = 29.5dBm, V <sub>DD</sub> = 2.8 to 3.0V		0.32	0.55	dB
	RF3-RF4	889 to 960MHz	Pin = 29.5dBm, V <sub>DD</sub> = 2.8 to 3.0V		0.30	0.55	dB
	RF5-RF2	810 to 885MHz	Pin = 7dBm, V <sub>DD</sub> = 2.8 to 3.0V		0.55	0.85	dB
	RF5-RF4	810 to 885MHz	Pin = 7dBm, V <sub>DD</sub> = 2.8 to 3.0V		0.55	0.85	dB
	RF5-RF1	810 to 885MHz	Pin = 7dBm, V <sub>DD</sub> = 2.8 to 3.0V		0.5	0.8	dB
	RF5-RF6	810 to 885MHz	Pin = 7dBm, V <sub>DD</sub> = 2.8 to 3.0V		0.5	0.8	dB
Isolation	RF3-RF2	889 to 960MHz	Pin = 29.5dBm, V <sub>DD</sub> = 2.8 to 3.0V	17	19		dB
	RF3-RF4	889 to 960MHz	Pin = 29.5dBm, V <sub>DD</sub> = 2.8 to 3.0V	17	21		dB
	RF5-RF2	810 to 885MHz	Pin = 7dBm, V <sub>DD</sub> = 2.8 to 3.0V	17	21		dB
	RF5-RF4	810 to 885MHz	Pin = 7dBm, V <sub>DD</sub> = 2.8 to 3.0V	17	19		dB
	RF5-RF1	810 to 885MHz	Pin = 7dBm, V <sub>DD</sub> = 2.8 to 3.0V	31	38		dB
	RF5-RF6	810 to 885MHz	Pin = 7dBm, V <sub>DD</sub> = 2.8 to 3.0V	24	29		dB
VSWR	Each ON Port	810 to 960MHz				1.4	
ACP (±50kHz)	RF3-RF2	889 to 960MHz	Pin = 29.5dBm, V <sub>DD</sub> = 3.0V*1		-67	-57	dBc
	RF3-RF4		Pin = 29.5dBm, V <sub>DD</sub> = 2.8V*1		-67	-55	dBc
ACP (±100kHz)	RF3-RF2	889 to 960MHz	Pin = 29.5dBm, V <sub>DD</sub> = 3.0V*1		-75	-65	dBc
	RF3-RF4		Pin = 29.5dBm, V <sub>DD</sub> = 2.8V*1		-75	-62	dBc
2nd harmonics	RF3-RF2	889 to 960MHz	Pin = 29.5dBm, V <sub>DD</sub> = 3.0V*1		-67	-60	dBc
	RF3-RF4		Pin = 29.5dBm, V <sub>DD</sub> = 2.8V*1		-67	-57	dBc
3rd harmonics	RF3-RF2	889 to 960MHz	Pin = 29.5dBm, V <sub>DD</sub> = 3.0V*1		-67	-60	dBc
	RF3-RF4		Pin = 29.5dBm, V <sub>DD</sub> = 2.8V*1		-67	-57	dBc
Control current					85	150	μA
Bias current			V <sub>DD</sub> = 3.0V		0.45	1	mA
			V <sub>DD</sub> = 2.8V		0.4	0.9	mA
Switching speed					1.0	5.0	μs

\*1 Input signal: ACP (±50kHz) < -65dBc, APC (±100kHz) < -75dBc,  
2nd harmonics < -65dBc, 3rd harmonics < -65dBc

## Electrical Characteristics 2

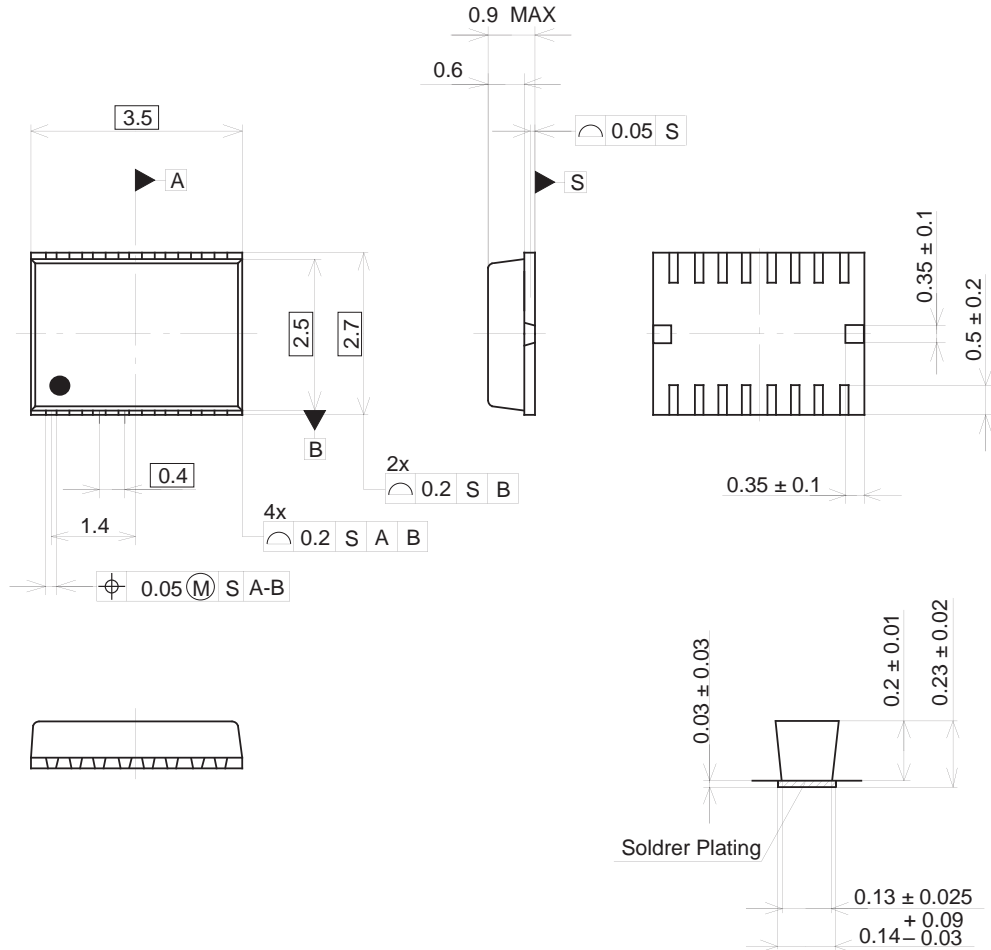
(V<sub>CTL</sub> (L) = 0V, V<sub>CTL</sub> (H) = 3V, Ta = 25°C)

Item		Frequency	Condition	Min.	Typ.	Max.	Unit
Insertion loss	RF3-RF2	1429 to 1453MHz	Pin = 29.5dBm, V <sub>DD</sub> = 2.8 to 3.0V		0.40	0.70	dB
	RF3-RF4	1429 to 1453MHz	Pin = 29.5dBm, V <sub>DD</sub> = 2.8 to 3.0V		0.40	0.70	dB
	RF5-RF2	1477 to 1501MHz	Pin = 7dBm, V <sub>DD</sub> = 2.8 to 3.0V		0.65	0.95	dB
	RF5-RF4	1477 to 1501MHz	Pin = 7dBm, V <sub>DD</sub> = 2.8 to 3.0V		0.65	0.95	dB
	RF5-RF1	1477 to 1501MHz	Pin = 7dBm, V <sub>DD</sub> = 2.8 to 3.0V		0.60	0.90	dB
	RF5-RF6	1477 to 1501MHz	Pin = 7dBm, V <sub>DD</sub> = 2.8 to 3.0V		0.60	0.90	dB
Isolation	RF3-RF2	1429 to 1453MHz	Pin = 29.5dBm, V <sub>DD</sub> = 2.8 to 3.0V	12	15		dB
	RF3-RF4	1429 to 1453MHz	Pin = 29.5dBm, V <sub>DD</sub> = 2.8 to 3.0V	15	18		dB
	RF5-RF2	1477 to 1501MHz	Pin = 7dBm, V <sub>DD</sub> = 2.8 to 3.0V	15	18		dB
	RF5-RF4	1477 to 1501MHz	Pin = 7dBm, V <sub>DD</sub> = 2.8 to 3.0V	13	16		dB
	RF5-RF1	1477 to 1501MHz	Pin = 7dBm, V <sub>DD</sub> = 2.8 to 3.0V	35	40		dB
	RF5-RF6	1477 to 1501MHz	Pin = 7dBm, V <sub>DD</sub> = 2.8 to 3.0V	20	25		dB
VSWR	Each ON Port	1429 to 1501MHz				1.4	
ACP (±50kHz)	RF3-RF2	1429 to 1453MHz	Pin = 29.5dBm, V <sub>DD</sub> = 3.0V*1		-67	-55	dBc
	RF3-RF4		Pin = 29.5dBm, V <sub>DD</sub> = 2.8V*1		-67	-53	dBc
ACP (±100kHz)	RF3-RF2	1429 to 1453MHz	Pin = 29.5dBm, V <sub>DD</sub> = 3.0V*1		-75	-65	dBc
	RF3-RF4		Pin = 29.5dBm, V <sub>DD</sub> = 2.8V*1		-75	-62	dBc
2nd harmonics	RF3-RF2	1429 to 1453MHz	Pin = 29.5dBm, V <sub>DD</sub> = 3.0V*1		-67	-60	dBc
	RF3-RF4		Pin = 29.5dBm, V <sub>DD</sub> = 2.8V*1		-67	-57	dBc
3rd harmonics	RF3-RF2	1429 to 1453MHz	Pin = 29.5dBm, V <sub>DD</sub> = 3.0V*1		-67	-57	dBc
	RF3-RF4		Pin = 29.5dBm, V <sub>DD</sub> = 2.8V*1		-67	-55	dBc
Control current					85	150	μA
Bias current			V <sub>DD</sub> = 3.0V		0.45	1	mA
			V <sub>DD</sub> = 2.8V		0.4	0.9	mA
Switching speed					1.0	5.0	μs

\*1 Input signal: ACP (±50kHz) < -65dBc, APC (±100kHz) < -75dBc,  
2nd harmonics < -65dBc, 3rd harmonics < -65dBc

Package Outline Unit: mm

16PIN VSON(PLASTIC)



NOTE:1) The dimensions of the terminal section apply to the ranges of 0.1mm and 0.25mm from the end of a terminal.

TERMINAL SECTION

PACKAGE STRUCTURE

SONY CODE	VSON-16P-01
EIAJ CODE	_____
JEDEC CODE	_____

PACKAGE MATERIAL	EPOXY RESIN
LEAD TREATMENT	SOLDER PLATING
LEAD MATERIAL	COPPER ALLOY
PACKAGE MASS	0.02 g